

High-pressure phases of a hydrogen-rich compound: TetramethylgermaneZhen-Xing Qin,¹ Chao Zhang,² Ling-Yun Tang,¹ Guo-Hua Zhong,³ Hai-Qing Lin,^{2,3} and Xiao-Jia Chen^{4,1,5}¹*Department of Physics, South China University of Technology, Guangzhou 510640, China*²*Beijing Computational Science Research Center, Beijing 100084, China*³*Shenzhen Institutes of Advanced Technology, Chinese Academy of Sciences, Shenzhen 518055, China*⁴*Geophysical Laboratory, Carnegie Institution of Washington, Washington, DC 20015, USA*⁵*Center for High Pressure Science and Technology Advanced Research, Shanghai 201203, China*

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The vibrational and structural properties of a hydrogen-rich group IVa hydride, $\text{Ge}(\text{CH}_3)_4$, are studied by combining Raman spectroscopy and synchrotron x-ray diffraction measurements at room temperature and at pressures up to 30.2 GPa. Both techniques allow the obtaining of complementary information on the high-pressure behaviors and yield consistent phase transitions at 1.4 GPa for the liquid to solid and 3.0, 5.4, and 20.3 GPa for the solid to solid. The four high-pressure solid phases are identified to have the cubic, orthorhombic, monoclinic, and monoclinic crystal structures with space groups of $Pa-3$ for phase I, $Pnma$ for phase II, $P2_1/c$ for phase III, and $P2_1$ for phase IV, respectively. These transitions are suggested to result from the changes in the inter- and intramolecular bonding of this compound. The softening of some Raman modes on CH_3 groups and their sudden disappearance indicate that $\text{Ge}(\text{CH}_3)_4$ might be an ideal compound to realize metallization and even high-temperature superconductivity at modest static pressure for laboratory capability.

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I. INTRODUCTION

The tetra-alkyl compounds of group IVa elements have attracted much attention from the scientific community due to their highly symmetrical character. The skeletal vibrations of their molecules have been investigated using Raman and infrared spectra since the 1930s.¹⁻¹² In the molecular structure of these compounds, the group IVa element is tetrahedrally coordinated by methyl groups (CH_3), making the molecule with the T_d symmetry. The CH_3 groups are expected to play an important role in understanding the interesting physical and chemical properties of the tetra-alkyl compounds of group IVa elements.¹³⁻¹⁹ At low temperature, the CH_3 groups become nonequivalent and exhibit intermolecular interactions.^{18,19} In addition, the CH_3 groups show various interesting behaviors at high pressures. Upon compression, the rotation of CH_3 groups have been restricted in some CH_3 -rich compounds, such as CH_3HgM ($M = \text{Cl}, \text{Br}, \text{I}$)²⁰ and $(\text{CH}_3)_2\text{XM}$ ($X = \text{Sn}$ or Tl).^{21,22} The CH_3 groups display different rotational angles in cubic $\text{Si}(\text{CH}_3)_4$ (TMS) at 0.58 GPa.²³ Therefore, understanding the behavior of CH_3 groups in the tetra-alkyl compounds of group IVa elements, especially the variance of CH_3 group under pressure, is important for condensed matter physics, materials science, and chemistry.

Group IVa hydrides also provide an alternative way to metallic hydrogen which was predicted to be a superconductor with high transition temperature in monatomic and molecular phases. In group IVa hydrides, the hydrogen atoms probably have undertaken chemical precompression by the group IVa atoms within the unit cell,²⁴ and thus the chemical pressure environments in these hydrides may greatly reduce the physical pressure necessary for metallic hydrogen. Several experimental and theoretical efforts are currently underway to examine this prediction, such as SiH_4 (Refs. 25–35), GeH_4 (Refs. 36–40), SnH_4 (Refs. 41–44), and PbH_4 (Ref. 45). However, very recently experiment shows the possible decomposition of SiH_4 under irradiation from x rays and lasers.^{46,47}

Excitingly, $\text{Si}(\text{CH}_3)_4$, one of the tetra-alkyl hydrides of group IVa elements, was found to be stable up to 140 GPa in our recent work,⁴⁸ although it remains insulating. Above 96 GPa, the sudden disappearing of original vibrational modes and appearing of new Raman modes make the metallization of tetramethylsilane more complex. In addition, it is suggested that the homologous hydrides with heavier group IVa atoms would yield lower metallization pressure, due to the weaker chemical bonds which can be dissociated at high pressures.⁴² Therefore, the investigation of heavier group IVa hydrides is in great demand.

Tetramethylgermane (TMGe), $\text{Ge}(\text{CH}_3)_4$, as one of heavier group IVa hydrides, belongs to a class of nonpolar molecular compounds [Fig. 1(a)]. At low temperature, only one modification of TMGe was observed in the temperature range 15–300 K.¹⁵ It was found that the entropy of the potential barrier to rotation of the CH_3 groups of TMGe is surprisingly low when considering the trends of the potential barriers in other methyl compounds of the group IV elements. Although the crystal structures of TMGe were predicted by global lattice-energy minimizations using force-field methods,¹⁴ no high-pressure phases have been determined experimentally. Therefore, it is of paramount importance to investigate the phase transitions and stability of TMGe under pressure, especially the inter- and intramolecular interactions of CH_3 groups.

In the present work, the high-pressure behaviors of TMGe are investigated by combining Raman scattering and synchrotron x-ray diffraction (XRD) techniques up to 30 GPa using the diamond anvil cells (DAC). Several possible phase transitions are identified at 1.4, 3.0, 5.4, and 20.3 GPa by Raman spectroscopy, and their structures are also determined based on the the obtained synchrotron XRD data. The variation of CH_3 groups with pressure is examined over the whole pressure range studied. The structural and vibrational features are provided and discussed for this hydrogen-bearing compound.

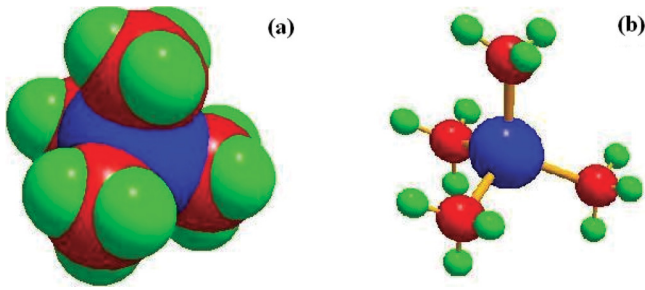


FIG. 1. (Color online) The configurations of TMGe with respect to ideally tetrahedral T_d ($-43m$) symmetry. (a) Cup model of TMGe shown to illustrate almost spherically shaped molecules in a close-packed stacking and (b) ball-and-stick model of TMGe manifested that one bond distance C-H, one Ge-C, one Ge-C-H/C-Ge-C angle could describe the molecular geometry.

II. EXPERIMENTAL DETAILS

TMGe (m.p. 185 K, b.p. 316 K) as transparency liquid with 98% purity was purchased from Alfa-Aesar and used without further purification. The high-pressure experiments for TMGe were carried out using DAC with culets of 300 μm . A hole of ~ 100 μm in diameter drilled in a preindented tungsten gasket served as the sample chamber. To avoid volatilizing, the bottom of the DAC was put into ice-water mixture half an hour before loading the sample. Liquid TMGe was loaded into the chamber of the DAC with a syringe. Because of the liquid sample, no pressure medium was used and ruby grains had been placed previously for calibrating pressure. Raman spectra were measured in a backscattering geometry with a spectrometer (with 1200 mm^{-1} grating) equipped with a dimonochromator and a charge coupled device detector, giving a resolution of 1–2 cm^{-1} . Radiation of 633 nm from a solid-state laser (50 mW CW) was used for the excitation of the Raman spectra and all spectra were measured at room temperature.

The same DAC was employed for the high-pressure synchrotron XRD experiment. Considering the volatilizing of samples, pressure was increased to 0.6 GPa after the sample was loaded. Synchrotron XRD data were collected at the X17C beamline at the National Synchrotron Light Source of Brookhaven National Laboratory via angle-dispersive diffraction techniques using monochromatic radiation $\lambda = 0.4067$ \AA . The sample-to-detector distance and the image plate orientation angles were calibrated using CeO_2 standard. The two-dimensional diffraction images were converted to 2θ versus intensity data plots using the FIT2D software.

In both measurements, the data shown here were collected in the compression cycle. However, we also performed the measurements in the decompression cycle. Our Raman scattering measurements confirmed that all the observations are reversible.

III. RESULTS AND DISCUSSION

A. High-pressure vibrational properties

In a single molecule of TMGe, the germanium atom is tetrahedrally bonded to four methyl groups, as shown in Fig. 1. For ideally tetrahedral T_d ($-43m$) molecular symmetry, one bond distance C-H, one Ge-C, and one Ge-C-H angle

would describe fully the molecular geometry. The methyl groups can be fully staggered with respect to the Ge-C bonds fully eclipsed or disordered [Fig. 1(b)]. The irreducible representation (of all the normal vibrational modes) is $\Gamma = 3A_1 + A_2 + 4E + 4F_1 + 7F_2$. According to the selection rule, the A_1 , E , and F_2 vibrations are Raman active. The measured modes at ambient conditions are summarized in Table I. Our data at ambient pressure are in good agreement with the results reported previously,^{4,49} except for the mode ν_5 . Due to the weak and broad inherent Raman signal, the value of mode ν_5 is not precise enough and thus it is omitted safely in the following discussion.

Vibrational spectroscopy is critical for characterizing the high-pressure behaviors of low-Z molecular compounds. Raman vibrational spectra of TMGe were collected from ambient pressure to high pressures up to 30.2 GPa, and the selected spectra are shown in Fig. 2. Clearly, the Raman spectra could be divided into four regions based on the molecular nature of the complex: the C-Ge-C skeletal deformation region (100–500 cm^{-1}), the C-Ge skeletal stretch region (500–800 cm^{-1}), the CH_3 symmetrical deformation region (1100–1300 cm^{-1}), and the CH_3 symmetrical and nonsymmetrical stretch region (2800–3300 cm^{-1}). With increasing pressure, all of the measured peaks shift to higher frequencies, and become weak at pressure up to 30.2 GPa. Some of peaks nearly vanish except for the $\nu_8 = 1400$ cm^{-1} and $\nu_9 = 1437$ cm^{-1} (the CH_3 nonsymmetrical deformation modes) which are influenced by the strong peak of diamond at 1332 cm^{-1} . This suggests that several pressure-induced phase transformations take place in TMGe.

The ν_1 and ν_2 modes in the C-Ge-C skeletal deformation region are very close to each other at ambient pressure [Fig. 3(a)], and thus are difficult to be identified. At the onset of compression, the intensities of the ν_1 and ν_2 modes exhibit reversal changes, yet recover soon, which is evidence for the exchange of the symmetry assignment of the ν_1 and ν_2 modes as a result of Fermi resonance.⁵⁰ Upon further compression up to 1.4 GPa, two new modes emerge, a lattice vibrational mode at the low-frequency region of 100–150 cm^{-1} and a mode (ν'_6) slightly locating below the mode ν_6 . The emergence of new vibrational modes, especially the lattice mode, can be identified to the liquid-solid state transition with the application of the external pressure. Furthermore, the sharp peak of the lattice mode suggests the new phase with higher ordered structure, which is also found in other compounds.⁵¹ With increasing pressure to 3.0 GPa, the Raman spectra change dramatically, indicating substantial changes in the crystal and/or molecular structures. As shown in Fig. 2, the peak of the lattice mode becomes sharper and its intensity increases at around 3.0 GPa. The most prominent change in the C-Ge-C skeletal deformation region is the merge of ν_1 and ν_2 modes. In addition, the ν_7 mode in the CH_3 symmetrical deformation region disappears at 3.0 GPa. Compressing continually to 5.4 GPa, the lattice mode ν_6 , which has a sharper peak at the pressure range of 1.4 to 3.0 GPa, broadens and weakens. Another mode in the CH_3 symmetrical deformation region also disappears. With continuous compression, there is no obvious change in the number of peaks in all four regions. These Raman modes only weaken and broaden with increasing pressure. This

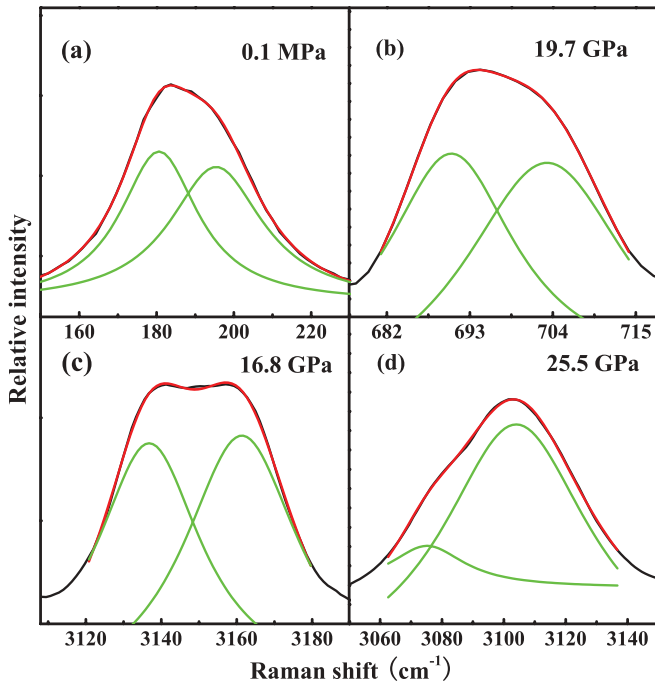


FIG. 3. (Color online) Comparison of observed and fitted Raman spectra of TMGe with respect to overlapped modes of (a) ν_1 and ν_2 at ambient conditions, (b) ν_4 with a shoulder at 19.7 GPa, (c) ν_{10} splitting with pressure up to 16.8 GPa, (d) ν_9 with a shoulder peak at 25.5 GPa. Black lines indicate observed Raman spectra; red lines through black lines indicate sum curve of the fit; the individual bands of the fit are represented by green lines in the lower part.

region of 30 GPa. In phase I, the mode ν'_6 of TMGe also undergoes blueshift, but its dv/dP is larger than those of the ν_6 and ν_7 modes, manifesting that new high-pressure structure is prone to be compressed. The pressure effect could be also observed in phases II and III in which a CH_3 rocking mode disappears and the C-Ge-C skeletal deformation modes merge. This indicates that CH_3 groups inside molecule are partly locked in the positions under pressure and the main skeleton of the molecules deforms due to the increased intra- and intermolecular interaction. In phase III, further compression restricts fully the movement from the deformation of CH_3 groups. At compression up to 16.8–20.3 GPa, the number of the Raman modes increases in the high-pressure phase IV, which indicates a new phase with lower symmetry.

Phase transformations are further identified by the changes of pressure coefficients of the Raman modes. The fitted pressure coefficients [dv/dP ($\text{cm}^{-1}/\text{GPa}$)] of the monitored peaks obtained by linear regression are listed in Table I. In general, most of the pressure coefficients of the stretch modes decrease noticeably with increasing pressure. From the liquid phase to phase I, the value of dv/dP of the modes ν_6 and ν_7 changes from negative to positive, indicating the rotational motion of the CH_3 groups is compelled to be frozen in positions.⁵⁰ Interestingly, there is an unusual case that high-pressure phase III possesses unexpected higher compressibility than that of phase II. This provides powerful evidence of phase transition, although the number of Raman peaks nearly does not change in both phases. Compared to

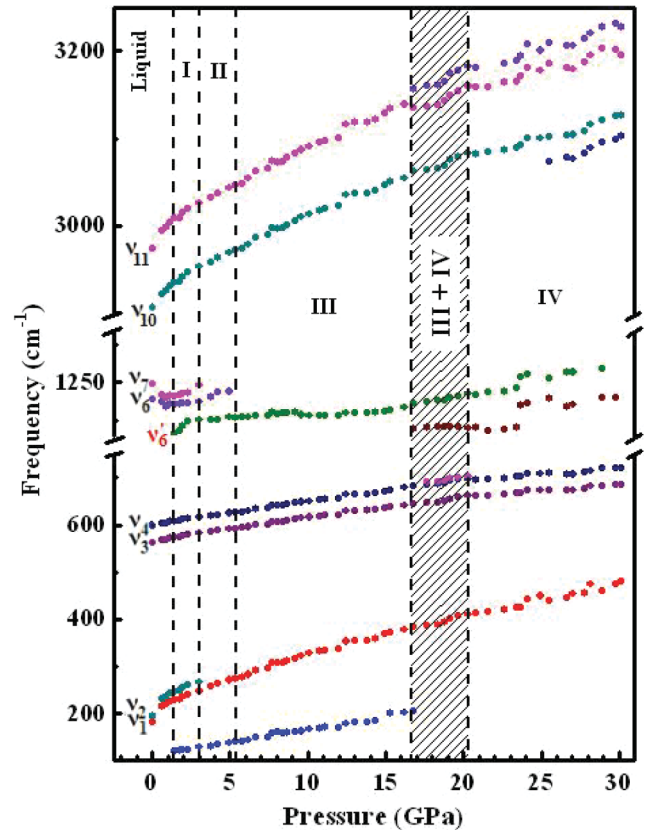


FIG. 4. (Color online) Pressure dependence of the frequencies of TMGe for the observed modes in all regions at room temperature. The vertical dashed lines at near 1.4, 3.0, 5.4, and 16.8–20.3 GPa indicate the proposed phase boundaries.

the pressure coefficients of phase II and III, phase IV shows a mutation in most of the Raman modes, which suggests that a new crystal structure would be made up with a closer packing of atoms.

Structural transformation at different temperatures and pressures has been a critical issue to explore the feasibility of metallic hydrides. Compared to TMS under pressure, TMGe exhibits rich phase transitions at low pressures. Especially for the CH_3 groups, no rotational mode in intrinsic spherically shaped molecules of TMGe at ambient conditions is assigned, yet it exhibits softening vibration related to the rotation of CH_3 group(s).^{20–22} Although the external pressure makes CH_3 groups of TMGe locked in the positions and restricts the mobility of the hydrogen atoms, it is uncertain whether all hydrogen atoms are built up in a network structure by means of the closest packing,^{52–54} which has significant implications for metallic hydrogen under pressure. Unfortunately, no direct evidence is found to illustrate the metallization of TMGe (i.e., visible darkening of the sample in the DAC) under pressure up to 30 GPa. Very recently, it has been reported that silane may undergo partial decomposition with compressed above 50 GPa, which hinders the search for the stable metallic hydrides. The high-pressure behaviors of TMGe, especially its stability and rich phase, manifest it as a candidate of hydrogen-rich material for achieving metallization at high pressures.

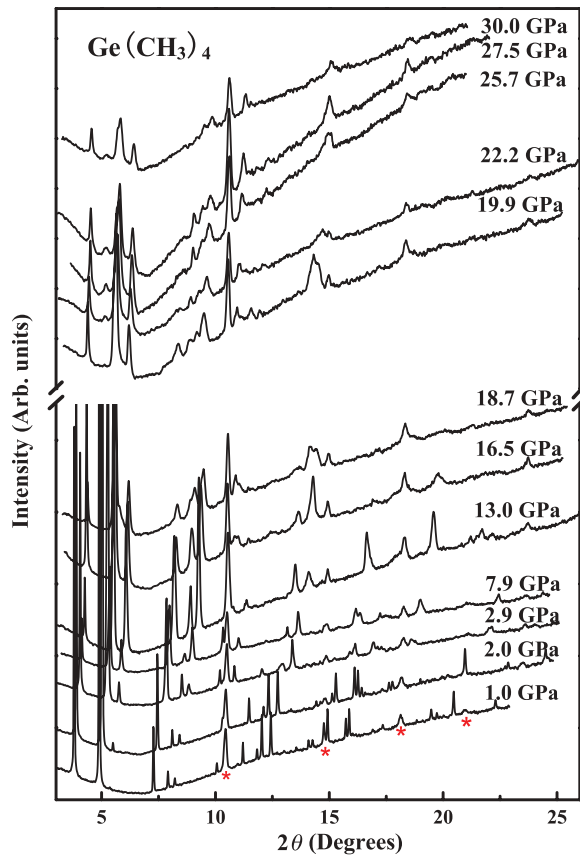


FIG. 5. (Color online) Synchrotron x-ray ($\lambda = 0.4067 \text{ \AA}$) diffraction patterns of TMGe during the pressurization from ambient conditions to 30.0 GPa. Red asterisk marked to illustrate the signals from the gasket material tungsten.

B. Determination of high-pressure phases

The pressure dependence of the scattering profile provides evidence for several phase transitions. Figure 5 shows the x-ray diffraction patterns of TMGe at pressures up to 30.0 GPa. All the Bragg peaks shift to larger angles, showing the shrinkage of the TMGe lattice. Upon compression to 2.9 GPa, there are several changes in the XRD patterns. The shape, intensity, and width of the peaks are distinct from low-pressure patterns in the region above 10° , and new peaks appear, which is consistent with the Raman results of phase transition at 3.0 GPa. In this pressure range, the changes of XRD patterns show the process of crystallization of TMGe from the liquid to solid state. With continuous compression to 7.9 GPa, obvious changes in the relative intensity of peaks are observed, which suggests the TMGe undergoes phase transition. This phase corresponds to the phase III observed in Raman spectroscopy above 5.4 GPa. Further compressed to 16.5 GPa, the XRD patterns again exhibit the changes in the number, intensity, and sharpness of peaks until 19.9 GPa, coinciding with phase IV from the Raman data. From 20.0 to 30.0 GPa, the XRD patterns remain stable with weak and broadening peaks. In the whole region of compression, several phase transitions determined by the XRD patterns are in accordance with those observed by Raman spectroscopy.

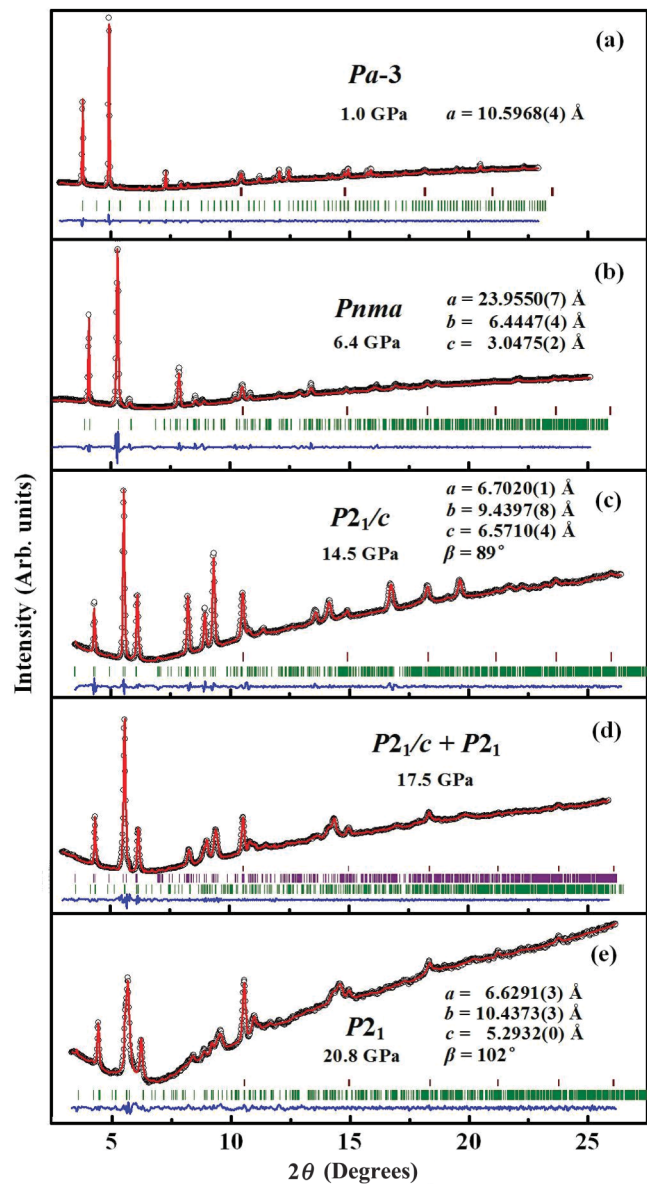


FIG. 6. (Color online) X-ray powder diffraction patterns of liquid TMGe at pressures of 1.0 (a), 6.4 (b), 14.5 (c), 17.5 (d), and 20.8 (e) GPa. The refined lattice parameters for the corresponding space groups are given respectively. The open circles represent the measured intensities and the red lines the results of profile refinements by the best LeBail fit with each space group. The positions of the Bragg reflections are marked by vertical lines and the difference profiles are shown at the bottoms (blue lines). The R values are $R_p = 0.7\%$, $R_{wp} = 1.0\%$ for the fitting at 1.0 GPa, $R_p = 0.8\%$, $R_{wp} = 1.6\%$ at 6.4 GPa, $R_p = 0.4\%$, $R_{wp} = 0.7\%$ at 14.5 GPa, $R_p = 0.3\%$, $R_{wp} = 0.6\%$ at 17.5 GPa, and $R_p = 0.3\%$, $R_{wp} = 0.5\%$ at 20.8 GPa.

To investigate the crystal structure of each phase, the diffraction patterns obtained at selected pressures were refined using the Le Bail method with GSAS software.⁵⁵ The phase I was fitted as the space group of $Pa-3$, and the measured and fitted data are shown in Fig. 6(a). The obtained space group of $Pa-3$ is consistent with the theoretical calculation,¹⁴ in which the $Pa-3$ phase was predicted by global lattice-energy minimizations using force-field methods. At 1.0 GPa, the

TMGe has the lattice parameter of $a = 10.5968(4)$ Å, which is similar to that of TMS. At 0.58 GPa and 296 K, TMS has a lattice parameter of $a = 10.7328$ Å (Ref. 23). In the $Pa-3$ phase, the molecules are situated on threefold axes, and thus CH_3 groups form a distorted cubic close packing, which is relatively rare among organic homomolecular crystals.⁵⁶

There is no information of crystal structure available at higher pressures for TMGe. The possible crystal structures of the unknown phases were analyzed with the program DICVOL06 (Ref. 57) and PEAKFIT v4. For phase II, 10 peaks were resolved at 2.9 GPa and indexed mainly to the orthorhombic system. As a minority, the cubic and tetragonal systems were ruled out due to unreasonable figures of merit (M, F) and/or volume of the cell. There are several space groups allowing for the orthorhombic phase, such as $Pnma$, $P2_12_12_1$, $Pbca$, $Ama2$, $Cmcm$, and $Pmn2_1$ from the predicted crystal structures of TMGe.¹⁴ Among them, $Pnma$ is a strong candidate for phase II because it shows better fit to the diffraction profile at 2.9 GPa. Additionally, the space group $Pnma$ ($Z = 4$) of TMGe was suggested as the second best structure energetically¹⁴ at ambient pressure. Figure 6(b) shows the fitted results of the phase II with $Pnma$ space group at 6.4 GPa with lattice parameters of $a = 23.9550(7)$ Å, $b = 6.4447(4)$ Å, and $c = 3.0475(2)$ Å.

For phase III of TMGe, the other 13 peaks from the XRD pattern at 7.9 GPa were resolved and indexed mainly to the monoclinic system and one orthorhombic system. Among the above plausible space group in orthorhombic system, the predicted volume per formula unit is 94.62 Å³ assuming $Z = 4$. However, this volume is illogical because it leads to considerable compressibility of 17 Å³/GPa per formula unit when comparing with the result of $V = 117.62$ Å³ per formula unit at 6.4 GPa. The related high-pressure studies on the sister compounds, $\text{C}(\text{Si}(\text{CH}_3)_3)_4$ (Ref. 58), $\text{Si}(\text{C}(\text{CH}_3)_3)_1(\text{Si}(\text{CH}_3)_3)_3$ (Ref. 59), and $\text{Si}(\text{C}(\text{CH}_3)_3)_2(\text{Si}(\text{CH}_3)_3)_2$ (Ref. 59), have found their small compressibilities below 6 GPa. For monoclinic system, it is difficult to determine the space group for this new phase, whereas $P2_1/c$ is a candidate because tetrahalides of the group IVa elements, MX_4 ($M = \text{Si}, \text{Ge}, \text{Sn}; X = \text{Cl}, \text{Br}$) with halogen atoms have a comparable size to a methyl group crystallized in $P2_1/c$, $Z = 4$ (Refs. 60–65). Additionally, the $P2_1/c$ space group with $Z = 4$ was also predicted as the third best structure of TMGe energetically and appeared repeatedly with increasing energy of crystal structure.¹⁴ Considering the Raman results that CH_3 groups are locked in positions and the whole groups move like one atom, the $P2_1/c$ space group would be the most reasonable solution to the structure of TMGe at 7.9 GPa. Figure 6(c) shows the result to fitting the patterns of TMGe at 14.5 GPa by the space group of $P2_1/c$. Compared to GeCl_4 ($a = 9.6903$ Å, $b = 6.4508$ Å, $c = 9.7740$ Å, and $\beta = 103.075^\circ$) and GeBr_4 ($a = 10.1832$ Å, $b = 6.7791$ Å, $c = 10.2922$ Å, and $\beta = 102.543^\circ$) at low temperature,^{63,65} the lattice parameters of $a = 6.7020(1)$ Å, $b = 9.4397(8)$ Å, $c = 6.5710(4)$ Å, and $\beta = 89.036^\circ$ are debatable. A plausible cause for the abnormality is nonhydrostatic situation of crystallized TMGe at pressure, which leads to the lattice distortion.

For phase IV, the diffraction patterns yield two orthorhombic systems and four monoclinic systems at 19.9 GPa.

According to the Raman results in phase IV, the number of Raman bands greatly increases, indicating the phase IV with lower symmetry. Along with the unreasonable values of $V = 637.90$ Å³ and $V = 617.87$ Å³ given in the lattice parameters of orthorhombic systems, the orthorhombic systems have been ruled out. For monoclinic systems, only one of the four lattice parameters with space group $P2_1$, $Z = 4$ in all of the monoclinic system was available for the corresponding systematic extinction rule. The lattice parameters are $a = 6.7127$ Å, $b = 10.5933$ Å, $c = 5.4200$ Å, and $\beta = 99.980^\circ$. Figure 6(e) shows the measured and fitted patterns of TMGe at 20.8 GPa. The problem still remains regarding whether space groups $P2$ and Pm in monoclinic system also conform to the XRD patterns in phase IV due to no constraint of the systematic extinction rule. Indeed, the refining results of $P2$ and Pm in the monoclinic system also bring out similar results to the case by $P2_1$ at phase IV. For the transient phase, only space group $P2_1$ and $P2_1/c$ are selected to fit the pattern at 17.5 GPa, as shown in Fig. 6(d).

C. Equations of state

To reveal the compressibility of each phase, the lattice parameters and volume per formula unit were computed by fitting the patterns at selected pressures from the GSAS software.⁵⁵ The changes of cell parameters are illustrated in Fig. 7, in which we only selected the $P2_1$ space group as a possible situation for phase IV, and Fig. 8 plots the pressure dependence of the volume per formula unit as a function of pressure for each phase. The volume/pressure relationship

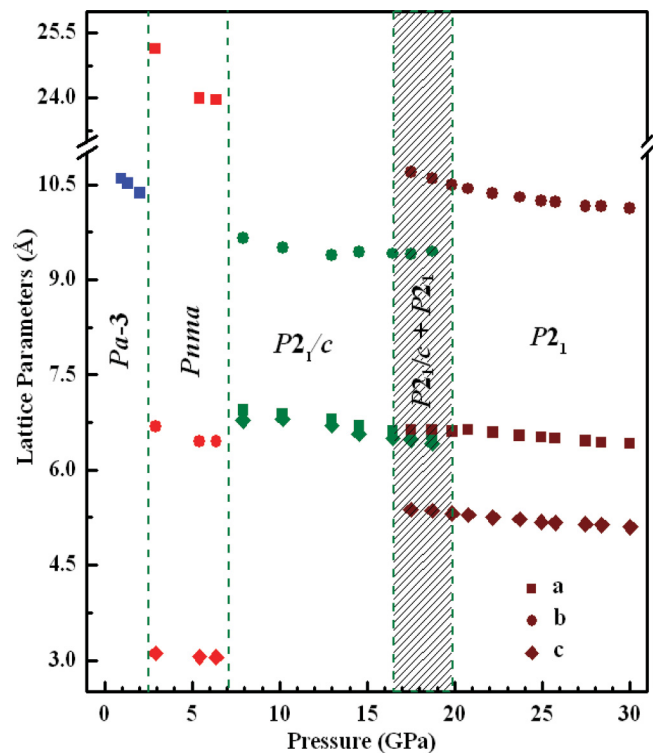


FIG. 7. (Color online) Pressure dependence of the lattice parameters' corresponding space groups for each phase; the vertical dashed lines denote the phase boundaries.

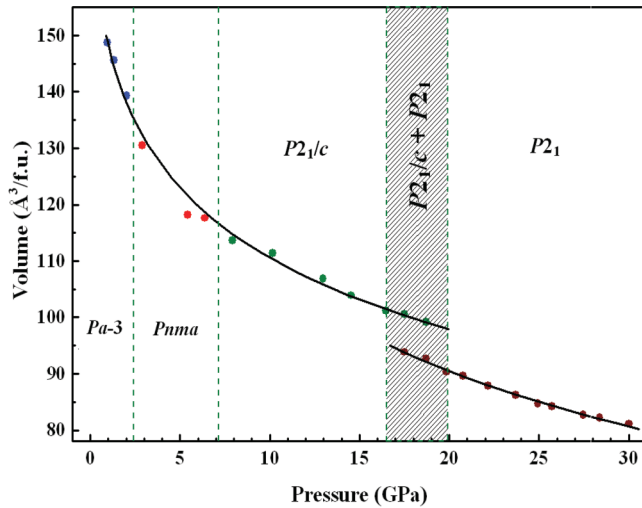


FIG. 8. (Color online) Volume per formula unit change of TMGe with pressure. The solid lines demonstrate the fitting data of phases to the Birch-Murnaghan equation of state and the vertical dashed lines denote the phase boundaries.

represents the equation of state (EoS), which can be described analytically by series expansions of Eulerian finite strain such as the Birch-Murnaghan equation of state (BM3 EoS)⁶⁶ defined as

$$P = 3K_0 f_E (1 + 2f_E)^{5/2} \left[1 + \frac{3}{2}(K'_0 - 4)f_E \right],$$

where $f_E = [(V_0/V)^{2/3} - 1]$, V_0 is the volume at ambient pressure, V is the volume at pressure P given in GPa, K_0 is the bulk modulus at 0 GPa, and K'_0 is the first pressure derivative of K_0 . The solid lines in Fig. 8 represent the fitted Birch-Murnaghan EoS, which yields more accurate parameters for highly compressible materials.

The bulk moduli of phase $Pa-3$, $Pnma$, and $P2_1/c$ are 2.19 ± 0.08 GPa with $K'_0 = 15.00 \pm 0.13$, $V_0 = 175.02 \pm 0.58 \text{ \AA}^3$, and phase $P2_1$ is 9.47 ± 0.65 GPa with $K'_0 = 4.00 \pm 0.01$, $V_0 = 167.26 \pm 3.07 \text{ \AA}^3$. For phase $Pa-3$, $Pnma$, and $P2_1/c$, the results are coincident with the analogous compound of $C(\text{Si}(\text{CH}_3)_3)_4$ (Ref. 58), indicating a soft feature. The increasing bulk moduli infer an enhancement of bond strength during phase transitions and indicate the intrinsic higher compressibility. It is worth mentioning that phase $P2_1$ has a relatively large bulk modulus compared with the high-pressure phases of TMS. This suggests that the crystal structure of phase $P2_1$ has been entirely transformed and that the layered network would be possible in view that the homologous compound, TMS, had started to form layers along the (011) lattice plane in the $Pnma$ phase at low temperature.¹⁴ The layered crystal structure for hydrogen atoms has been suggested to be an essential metallic state in hydrogen-bearing compounds.^{25,29,38,42,67} Furthermore, the bulk modulus in phase $P2_1$ is of remarkable strength because silane (SiH_4) has gotten the bulk modulus of 7.89 GPa upon being compressed to 39 GPa (Ref. 28) and the $\text{SiH}_4\text{-H}_2$ complex has also achieved the value of 6.87 GPa with pressure up to 35 GPa (Ref. 68), whereas methane (CH_4) could get the same value only by compressing

to 13 GPa (Ref. 69). Recently, high-pressure studies^{70,71} on hydrogen-rich germanium compounds $\text{GeH}_4\text{-H}_2$ revealed very rich vibrational dynamics, intermolecular interactions, and structural, electronic, and potential superconducting properties.

So far, there is little information on such a magnitude of hydrogen-bearing compound TMGe. Measurements of electronic transport properties are expected to be performed in order to examine whether TMGe would undergo metallization and eventually become a superconductor at higher pressures. It should be noticed that a recent electronic transport study on molecular hydrogen revealed a significant resistance drop at 260–270 GPa (Ref. 72). However, two independent measurements^{73,74} indicate that metallic hydrogen has not been reached yet even at 360 GPa. The softening of some Raman modes on CH_3 groups and their sudden disappearance in $\text{Ge}(\text{CH}_3)_4$ indicate that this compound might be ideal for metallization and even high-temperature superconductivity at modest static pressure for laboratory capability.

IV. CONCLUSIONS

We performed Raman measurements of TMGe at room temperature and at pressures up to 30 GPa. Our results revealed the phase transitions at 1.4, 3.0, 5.4, and 20.3 GPa from the mode frequency shifts with pressure. We found that phase transitions of TMGe are more sensitive to pressure than those of tetramethylsilane. These transitions were suggested to result from the changes in the inter- and intramolecular bonding of this material. Further work using synchrotron x-ray radiation revealed three phase transitions at 2.9, 7.9, and 19.9 GPa with similar results from Raman measurements. The space groups for the high-pressure phases were determined to be $Pa-3$ for phase I, $Pnma$ for phase II, $P2_1/c$ for phase III, and $P2_1$ for phase IV. The equations of state were obtained up to 30 GPa. Such structural information may be helpful in exploring possible superconductivity in hydrogen-bearing compounds at high pressures.

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